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SFT1458

N-Channel Power MOSFET 600V, 1.0A, 13Ω, Single TP/TP-FA

Features

- On-resistance $R_{DS(on)}=10\Omega$ (typ.)
- Input Capacitance $C_{iss}=65pF$ (typ.)
- Protection Diode in
- 10V drive
- Halogen free compliance

Specifications

Absolute Maximum Ratings at $T_a = 25^\circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Drain to Source Voltage	V_{DSS}		600	V
Gate to Source Voltage	V_{GSS}		± 30	V
Drain Current (DC)	I_D		1	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	4	A
Allowable Power Dissipation	P_D		1	W
		$T_c=25^\circ C$	38	W
Channel Temperature	T_{ch}		150	$^\circ C$
Storage Temperature	T_{stg}		-55 to +150	$^\circ C$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

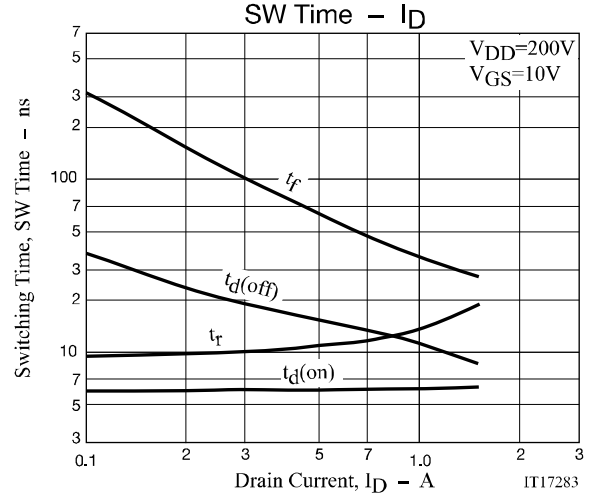
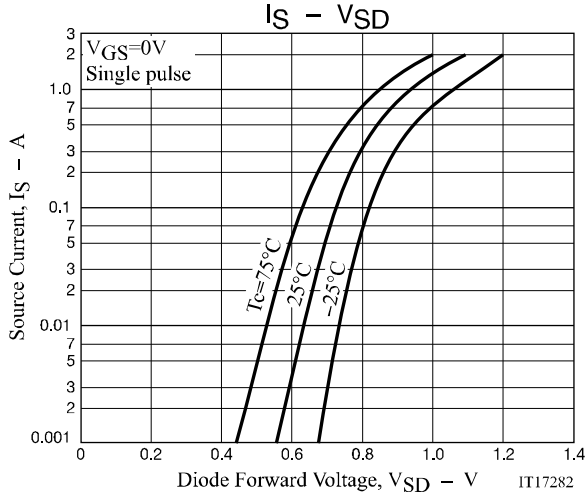
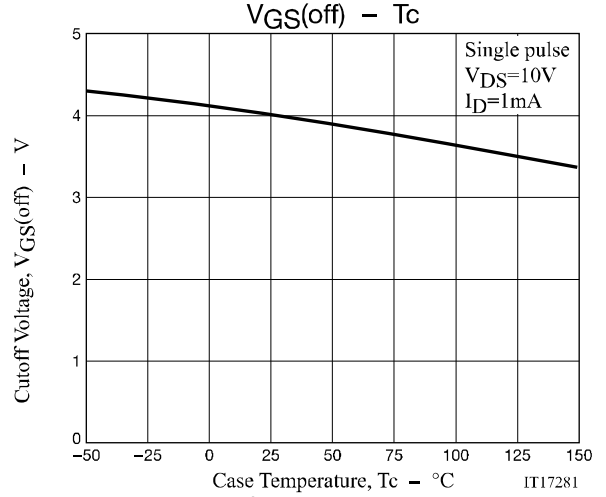
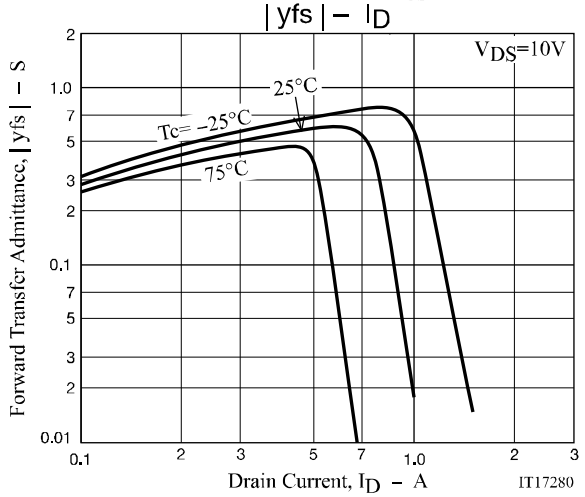
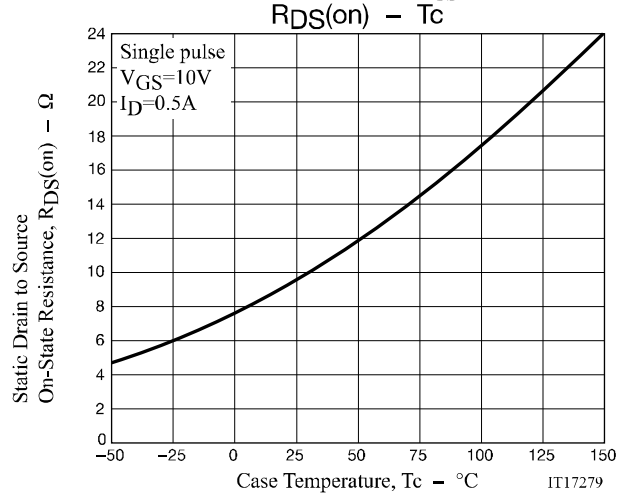
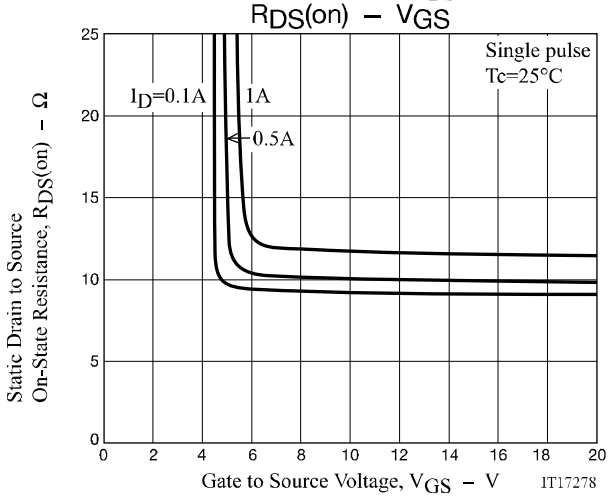
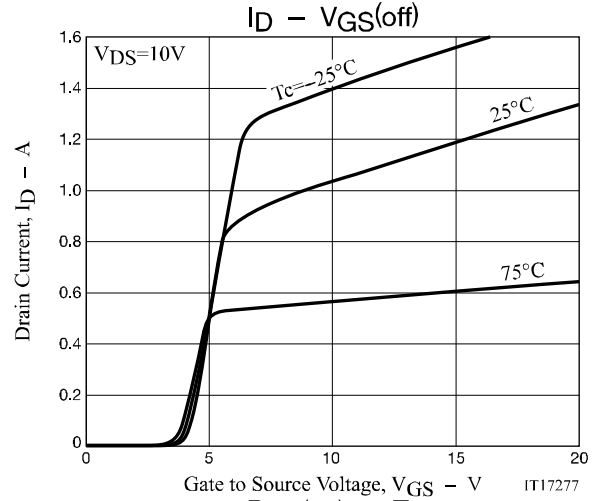
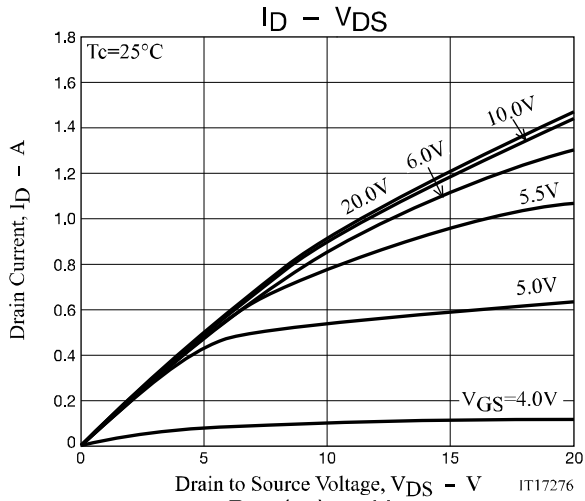
Electrical Characteristics at $T_a = 25^\circ C$

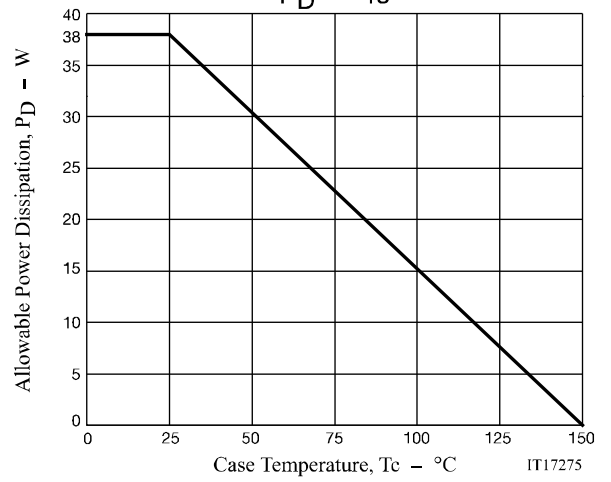
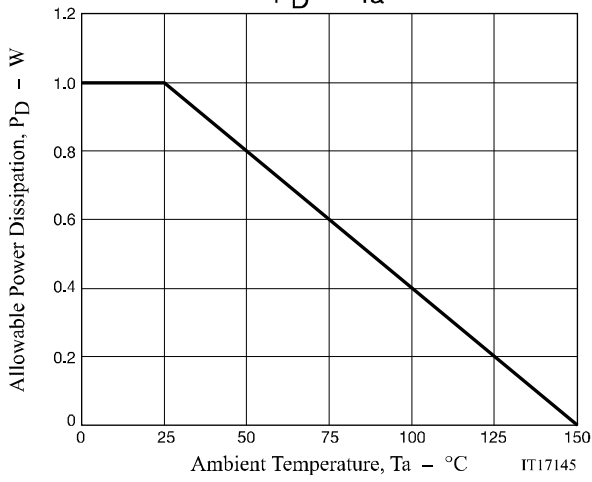
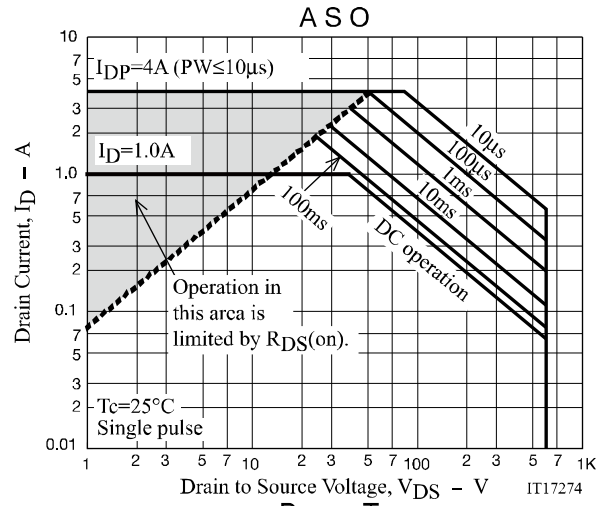
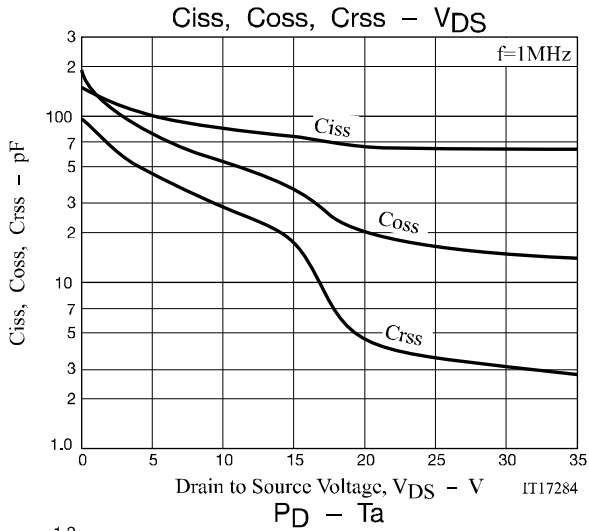
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=10mA$, $V_{GS}=0V$	600			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=480V$, $V_{GS}=0V$			100	μA
Gate to Source Leakage Current	I_{GSS}	$V_{GS}=\pm 24V$, $V_{DS}=0V$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=10V$, $I_D=1mA$	3.5		4.5	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=10V$, $I_D=0.5A$		0.57		S
Static Drain to Source On-State Resistance	$R_{DS(on)}$	$I_D=0.5A$, $V_{GS}=10V$		10	13	Ω
Input Capacitance	C_{iss}	$V_{DS}=20V$, $f=1MHz$		65		pF
Output Capacitance	C_{oss}			20		pF
Reverse Transfer Capacitance	C_{rss}			4.5		pF
Turn-ON Delay Time	$t_{d(on)}$				6	ns
Rise Time	t_r	See specified Test Circuit.		11		ns
Turn-OFF Delay Time	$t_{d(off)}$				12	ns
Fall Time	t_f				60	ns
Total Gate Charge	Q_g	$V_{DS}=200V$, $V_{GS}=10V$, $I_D=1A$		3.8		nC
Gate to Source Charge	Q_{gs}			0.54		nC
Gate to Drain "Miller" Charge	Q_{gd}			2.3		nC
Diode Forward Voltage	V_{SD}	$I_S=1A$, $V_{GS}=0V$		0.93	1.2	V

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

SFT1458





Package Dimensions

SFT1458-H

IPAK/TP

CASE 369AL

ISSUE O

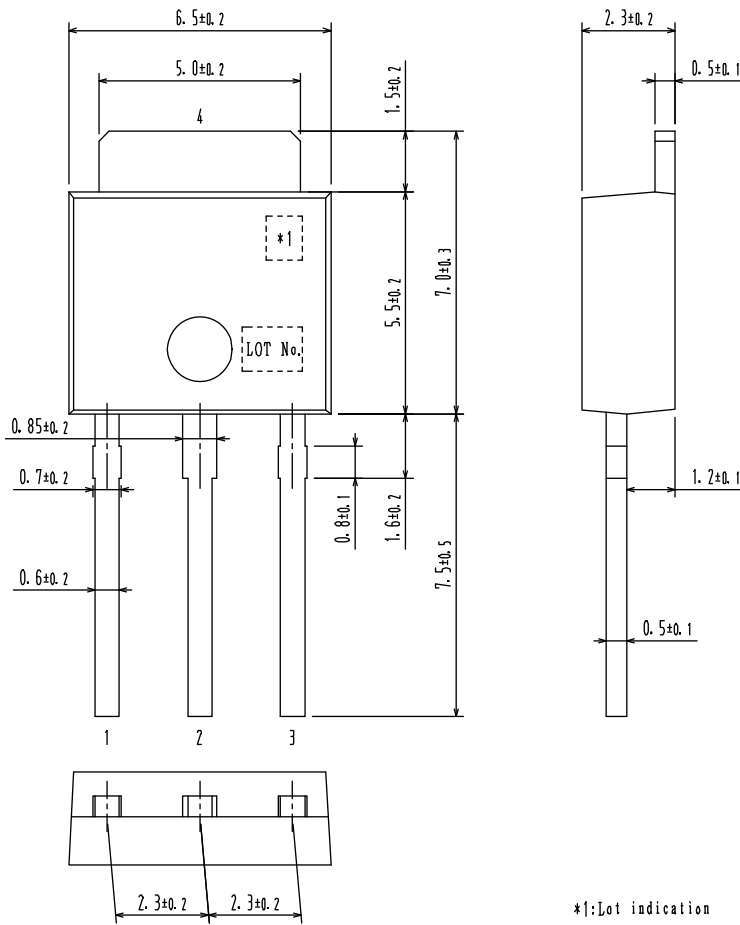
Unit : mm

1: Gate

2: Drain

3: Source

4: Drain



*1: Lot indication

Package Dimensions

SFT1458-TL-H

DKPAK/TP-FA

CASE 369AH

ISSUE O

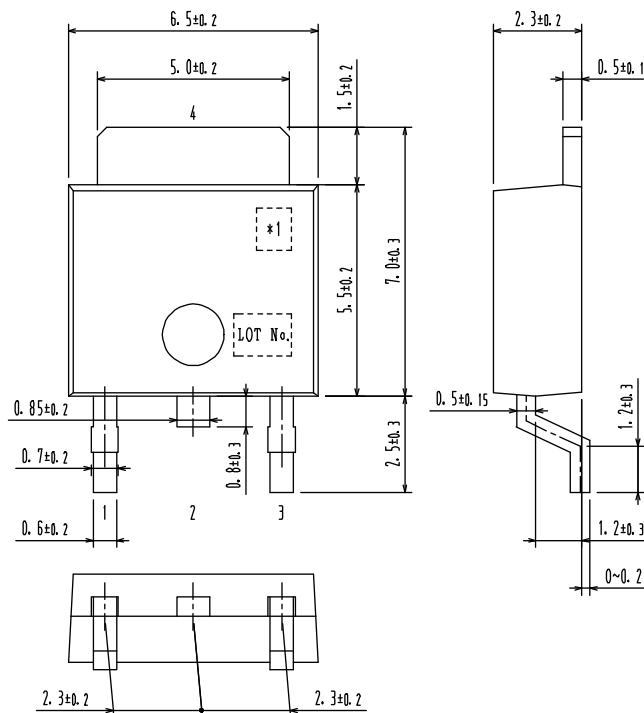
Unit : mm

1: Gate

2: Drain

3: Source

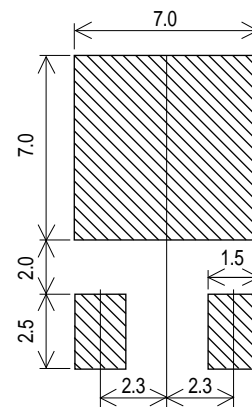
4: Drain



Pin 2 is idle pin with electrical designation only carried.

*1: Lot indication

Land Pattern Example

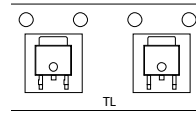


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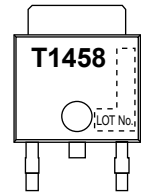
Ordering & Package Information

Device	Package	Shipping	note
SFT1458-H	TP SC-64, TO-251, SOT-553, DPAK	500 pcs. / bag	Pb-Free And Halogen Free
SFT1458-TL-H	TP-FA SC-63, TO-252, SOT-428, DPAK	700 pcs. / reel	

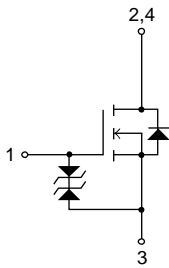
Packing Type: TL



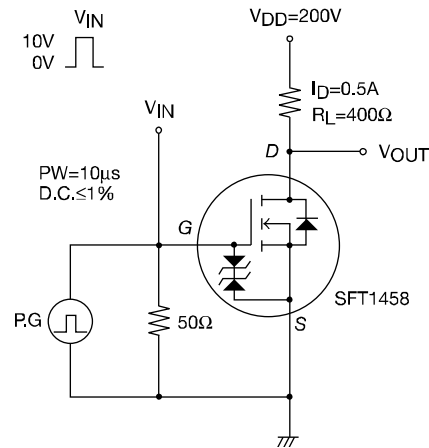
Marking



Electrical Connection



Switching Time Test Circuit



Note on usage : Since the SFT1458 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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